

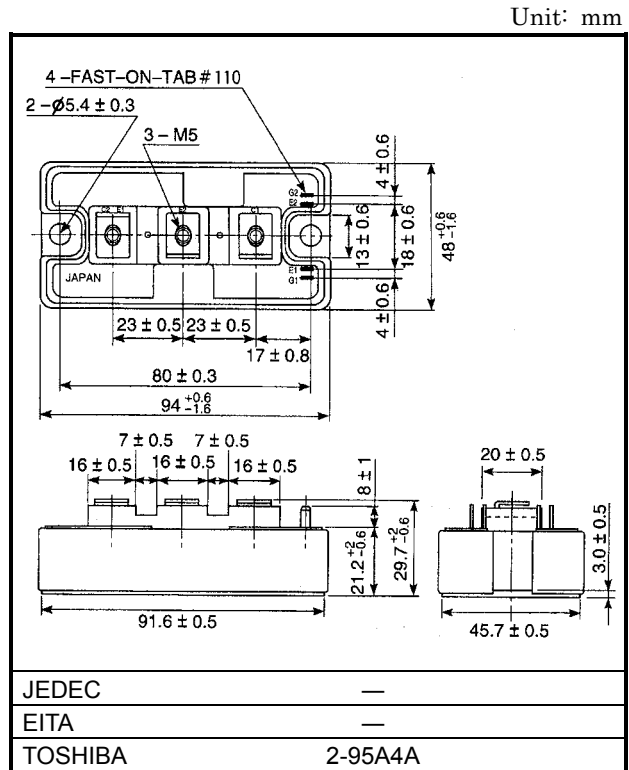
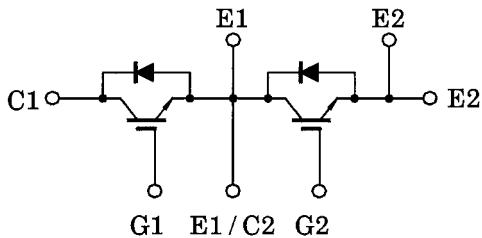
TOSHIBA GTR Module Silicon N Channel IGBT

MG150Q2YS50

High Power Switching Applications
 Motor Control Applications

- High input impedance
- High speed : $t_f = 0.3\mu s$ (Max)
 @Inductive load
- Low saturation voltage
 : $V_{CE(sat)} = 3.6V$ (Max)
- Enhancement-mode
- Includes a complete half bridge in one package.
- The electrodes are isolated from case.

Equivalent Circuit



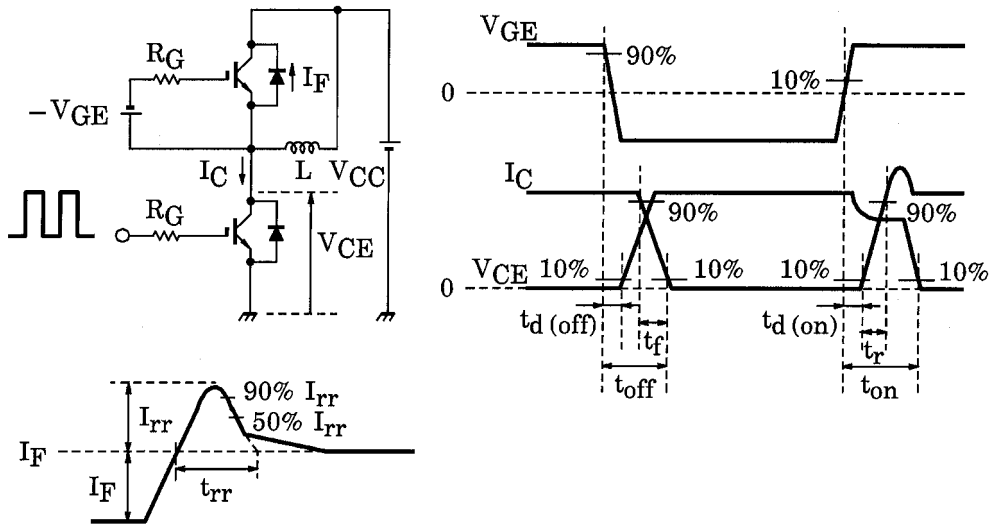
Maximum Ratings (Ta = 25°C)

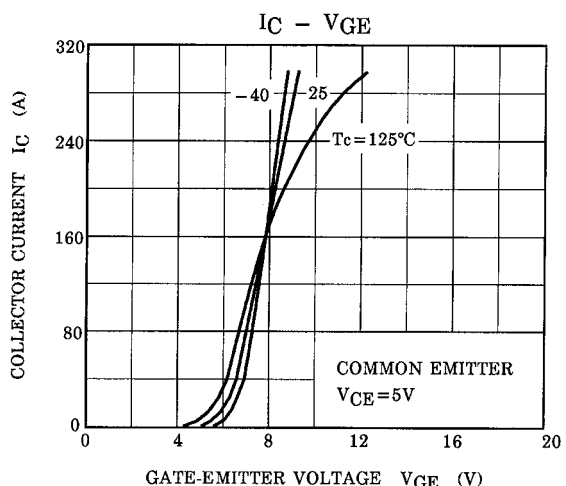
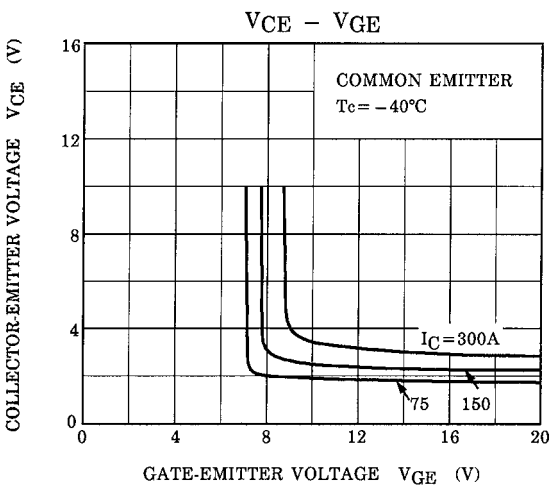
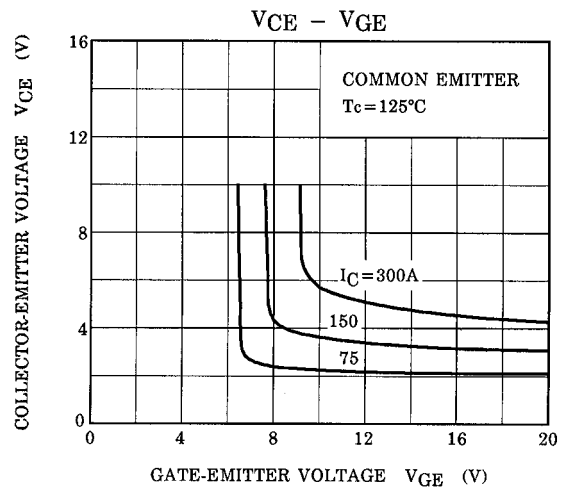
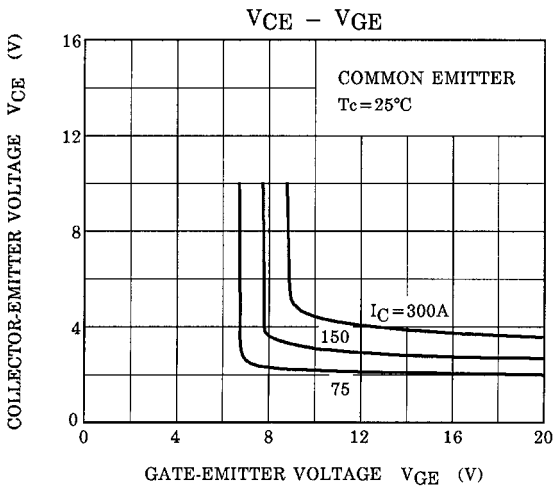
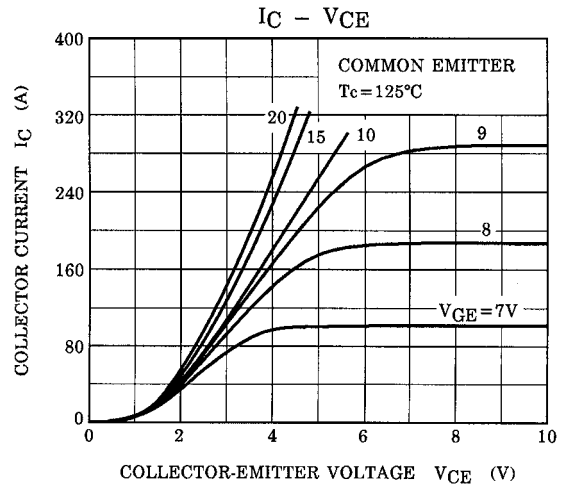
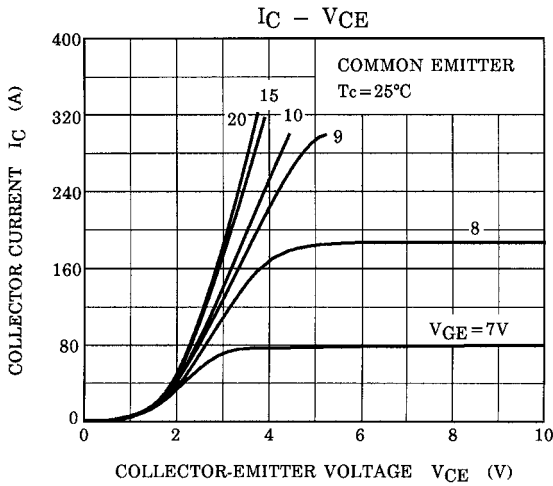
Characteristic	Symbol	Rating	Unit
Collector-emitter voltage	V_{CES}	1200	V
Gate-emitter voltage	V_{GES}	±20	V
Collector current	DC	I_C (25°C / 80°C)	200 / 150
	1ms	I_{CP} (25°C / 80°C)	400 / 300
Forward current	DC	I_F	150
	1ms	I_{FM}	300
collector power dissipation (Tc = 25°C)	P_C	1250	W
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-40 ~ 125	°C
Isolation voltage	V_{Isol}	2500 (AC 1 min.)	V
Screw torque (Terminal / mounting)	—	3 / 3	N·m

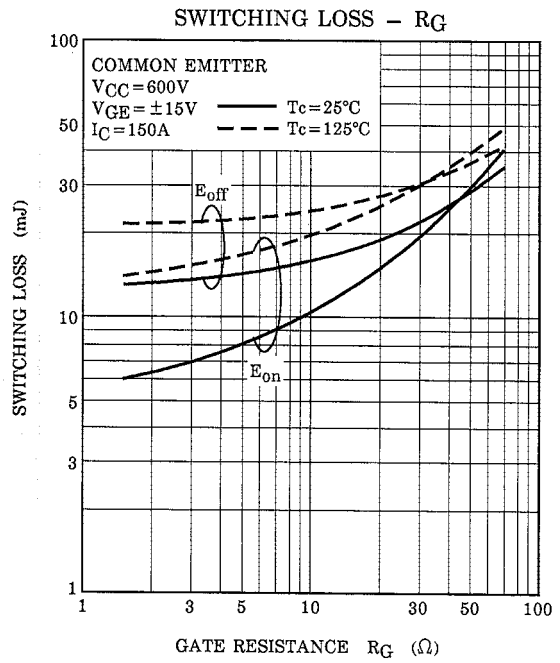
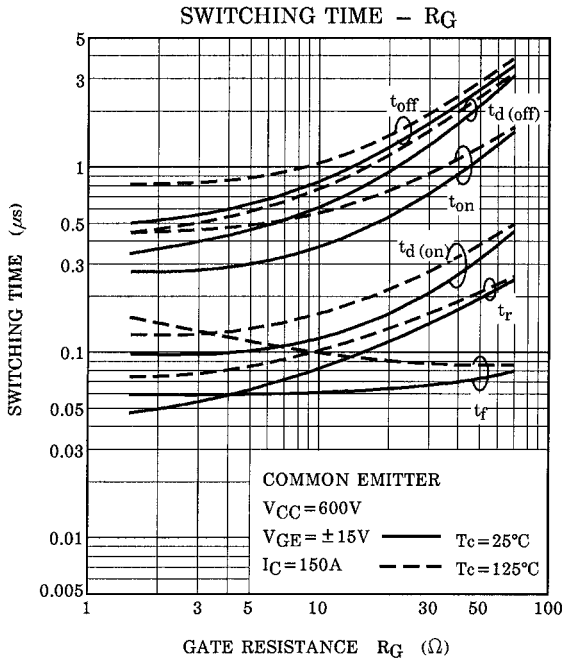
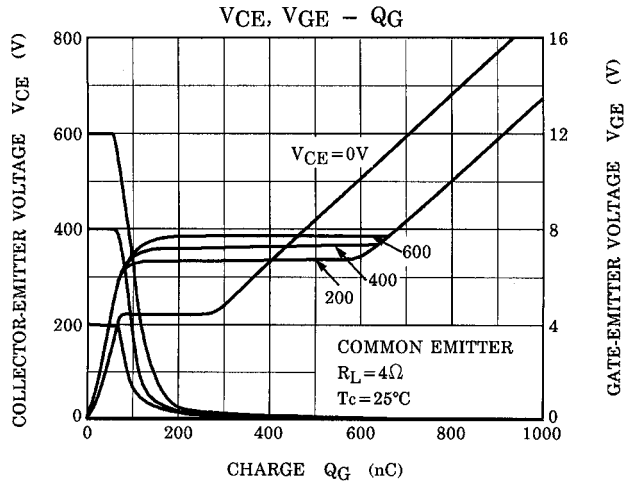
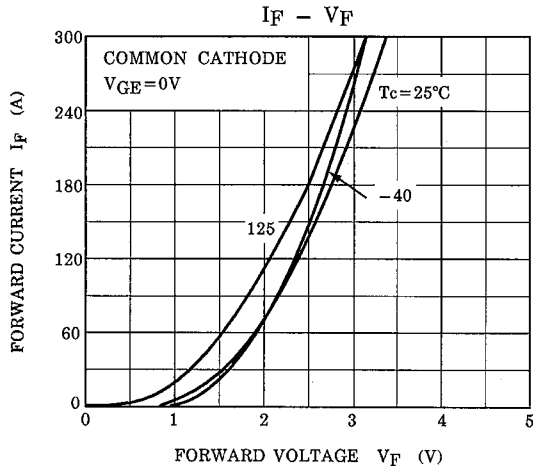
Electrical Characteristics (Ta = 25°C)

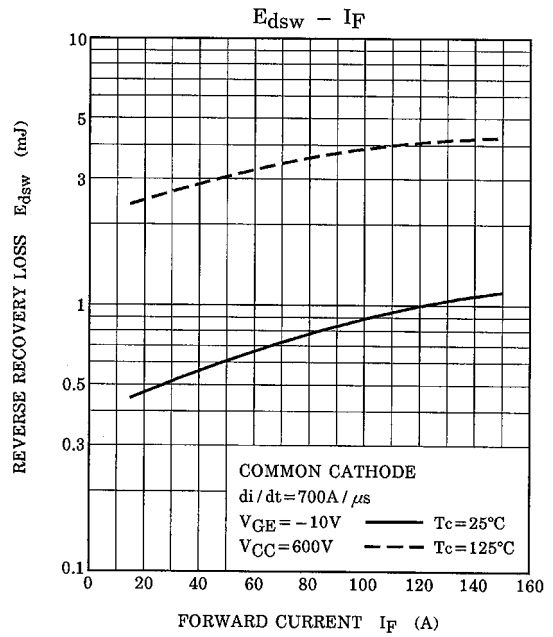
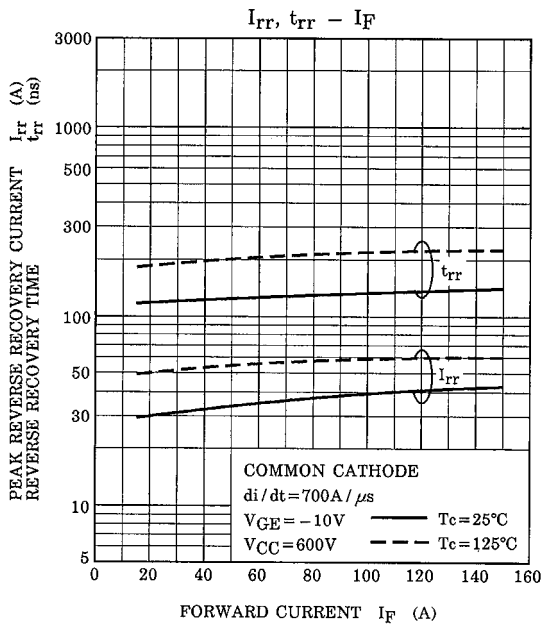
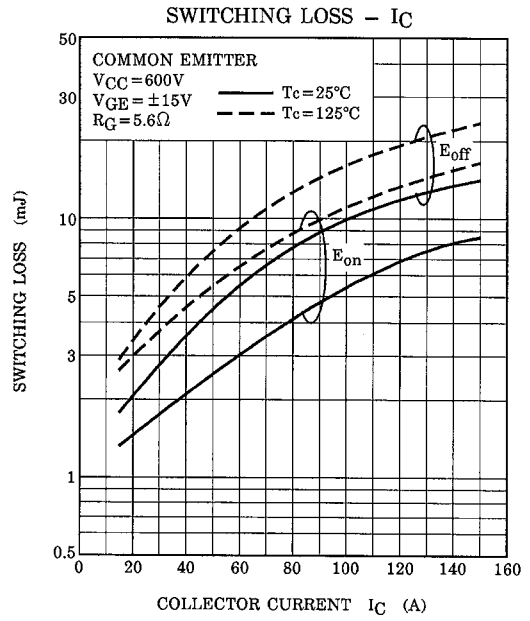
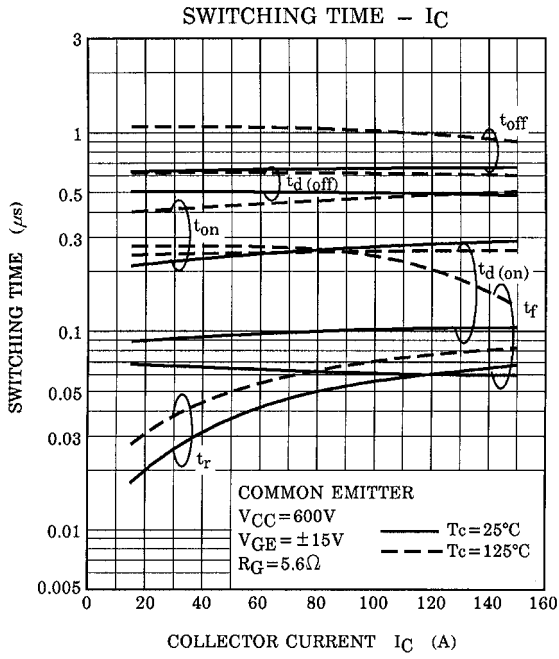
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	I_{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	± 500	nA	
Collector cut-off current	I_{CES}	$V_{CE} = 1200V, V_{GE} = 0$	—	—	2.0	mA	
Gate-emitter cut-off voltage	$V_{GE(off)}$	$I_C = 150mA, V_{CE} = 5V$	3.0	—	6.0	V	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 150A, V_{GE} = 15V$	$T_j = 25^\circ C$	—	2.8	3.6	V
			$T_j = 125^\circ C$	—	3.1	4.0	
Input capacitance	C_{ies}	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	18.0	—	nF	
Switching time	Turn-on delay time	$t_{d(on)}$	—	0.05	—	μs	
	Rise time	t_r	Inductive load $V_{CC} = 600V$ $I_C = 150A$ $V_{GE} = \pm 15V$ $R_G = 5.6\Omega$ (Note 1)	—	0.05		—
	Turn-on time	t_{on}		—	0.2		—
	Turn-off delay time	$t_{d(off)}$		—	0.5		—
	Fall time	t_f		—	0.1		0.3
	Turn-off time	t_{off}		—	0.6		—
Forward voltage	V_F	$I_F = 150A, V_{GE} = 0$		—	2.4	3.5	V
Reverse recovery time	t_{rr}	$I_F = 150A, V_{GE} = -10V$ $di/dt = 700A/\mu s$ (Note 1)	—	0.1	0.25	μs	
Thermal resistance	$R_{th(j-c)}$	Transistor stage	—	—	0.1	$^\circ C/W$	
		Diode stage	—	—	0.32		

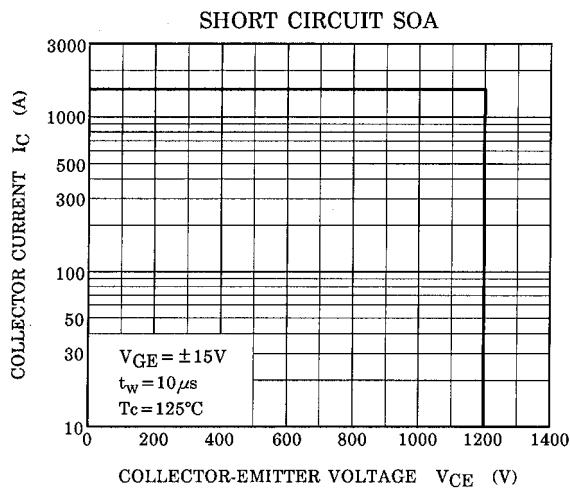
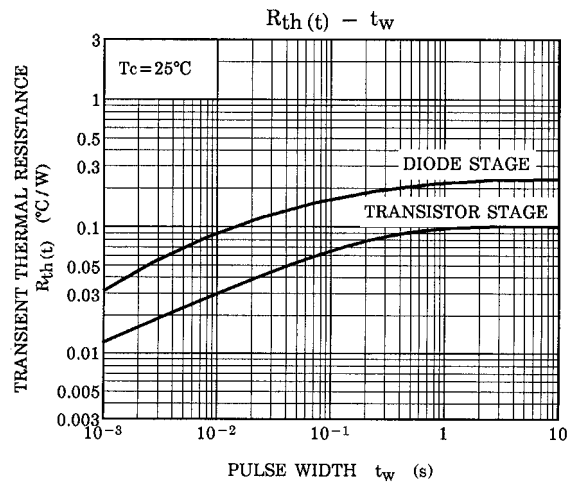
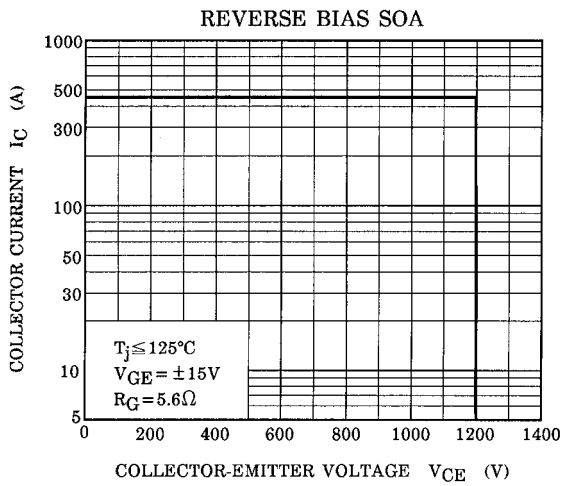
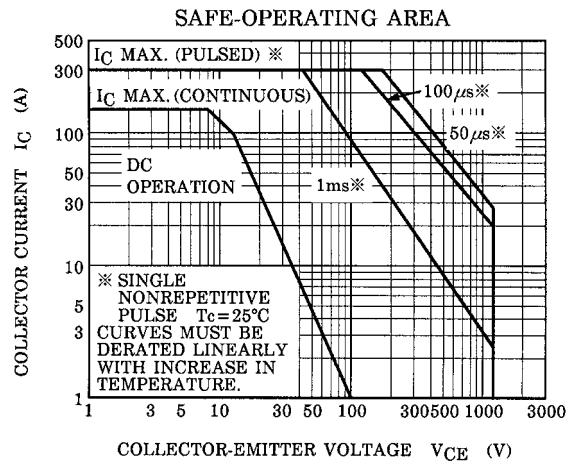
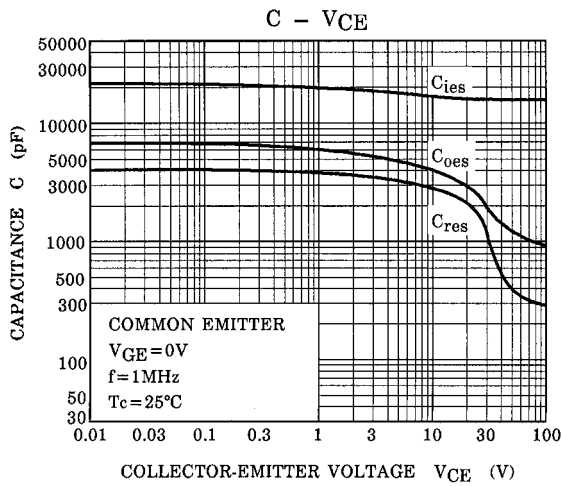
Note 1: Switching time and reverse recovery time test circuit & timing chart











RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.